Chipsmall Limited consists of a professional team with an average of over 10 year of expertise in the distribution of electronic components. Based in Hongkong, we have already established firm and mutual-benefit business relationships with customers from,Europe,America and south Asia,supplying obsolete and hard-to-find components to meet their specific needs.

With the principle of “Quality Parts,Customers Priority,Honest Operation,and Considerate Service”,our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip,ALPS,ROHM,Xilinx,Pulse,ON,Everlight and Freescale. Main products comprise IC,Modules,Potentiometer,IC Socket,Relay,Connector.Our parts cover such applications as commercial,industrial, and automotives areas.

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Tel: +86-755-8981 8866 Fax: +86-755-8427 6832
Email & Skype: info@chipsmall.com Web: www.chipsmall.com
Address: A1208, Overseas Decoration Building, #122 Zhenhua RD., Futian, Shenzhen, China

N-Channel Power MOSFET

600V, 18A, 0.19Ω

FEATURES

- Super-Junction technology
- High performance, small $R_{DS(ON)}$*Q_g figure of merit (FOM)
- High ruggedness performance
- 100% UIS and R_g tested
- Compliant to RoHS Directive 2011/65/EU and in accordance to WEEE 2002/96/EC
- Halogen-free according to IEC 61249-2-21

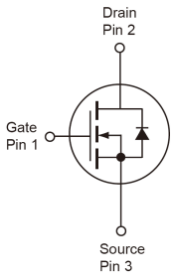
APPLICATIONS

- Power Supply
- AC/DC LED Lighting

KEY PERFORMANCE PARAMETERS		
PARAMETER	**VALUE**	**UNIT**
V_{DS}	600	V
$R_{DS(on)}$ (max)	0.19	Ω
Q_g	32	nC

Pb-Free RoHS COMPLIANT HALOGEN FREE

ITO-220S



ABSOLUTE MAXIMUM RATINGS (T_A = 25°C unless otherwise noted)				
PARAMETER		**SYMBOL**	**LIMIT**	**UNIT**
Drain-Source Voltage		V_{DS}	600	V
Gate-Source Voltage		V_{GS}	±30	V
Continuous Drain Current (Note 1)	T_C = 25°C	I_D	18	A
	T_C = 100°C		11	A
Pulsed Drain Current (Note 2)		I_{DM}	54	A
Total Power Dissipation @ T_C = 25°C		P_D	59.5	W
Single Pulse Avalanche Energy (Note 3)		E_{AS}	441	mJ
Single Pulse Avalanche Current (Note 3)		I_{AS}	4.2	A
Operating Junction and Storage Temperature Range		T_J, T_{STG}	- 55 to +150	°C

THERMAL PERFORMANCE			
PARAMETER	**SYMBOL**	**LIMIT**	**UNIT**
Junction to Case Thermal Resistance	$R_{\Theta JC}$	2.1	°C/W
Junction to Ambient Thermal Resistance	$R_{\Theta JA}$	62	°C/W

Thermal Performance Note: $R_{\Theta JA}$ is the sum of the junction-to-case and case-to-ambient thermal resistances. The case-thermal reference is defined at the solder mounting surface of the drain pins. $R_{\Theta JA}$ is guaranteed by design while $R_{\Theta CA}$ is determined by the user's board design.

ELECTRICAL SPECIFICATIONS (T_A = 25°C unless otherwise noted)						
PARAMETER	**CONDITIONS**	**SYMBOL**	**MIN**	**TYP**	**MAX**	**UNIT**
Static						
Drain-Source Breakdown Voltage	V_{GS} = 0V, I_D = 250μA	BV_{DSS}	600	--	--	V
Gate Threshold Voltage	V_{DS} = V_{GS}, I_D = 250μA	$V_{GS(TH)}$	2	3.2	4	V
Gate Body Leakage	V_{GS} = ±30V, V_{DS} = 0V	I_{GSS}	--	--	±100	nA
Zero Gate Voltage Drain Current	V_{DS} = 600V, V_{GS} = 0V	I_{DSS}	--	--	1	μA
Drain-Source On-State Resistance **(Note 4)**	V_{GS} = 10V, I_D = 3.7A	$R_{DS(on)}$	--	0.17	0.19	Ω
Dynamic **(Note 5)**						
Total Gate Charge	V_{DS} = 480V, I_D = 11A, V_{GS} = 10V	Q_g	--	32	--	nC
Gate-Source Charge		Q_{gs}	--	8	--	
Gate-Drain Charge		Q_{gd}	--	14	--	
Input Capacitance	V_{DS} = 100V, V_{GS} = 0V, f = 1.0MHz	C_{iss}	--	1311	--	pF
Output Capacitance		C_{oss}	--	71	--	
Reverse Transfer Capacitance		C_{rss}	--	4	--	
Gate Resistance	f = 1.0MHz	R_g	--	3	6	Ω
Switching **(Note 6)**						
Turn-On Delay Time	V_{DD} = 300V, R_{GEN} = 5Ω, I_D = 11A, V_{GS} = 10V,	$t_{d(on)}$	--	11	--	ns
Turn-On Rise Time		t_r	--	34	--	
Turn-Off Delay Time		$t_{d(off)}$	--	26	--	
Turn-Off Fall Time		t_f	--	17	--	
Source-Drain Diode						
Body-Diode Continuous Forward Current		I_S	--	--	18	A
Body-Diode Pulsed Current		I_{SM}	--	--	54	A
Forward Voltage **(Note 4)**	I_S = 11A, V_{GS} = 0V	V_{SD}	--	--	1.4	V
Reverse Recovery Time	I_S = 11A dI$_F$/dt = 100A/μs	t_{rr}	--	288	--	ns
Reverse Recovery Charge		Q_{rr}	--	4.1	--	μC

Notes:

1. Current limited by package.
2. Pulse width limited by the maximum junction temperature.
3. L = 50mH, I_{AS} = 4.2A, V_{DD} = 50V, R_G = 25Ω, Starting T_J = 25°C
4. Pulse test: PW ≤ 300μs, duty cycle ≤ 2%.
5. For DESIGN AID ONLY, not subject to production testing.
6. Switching time is essentially independent of operating temperature.

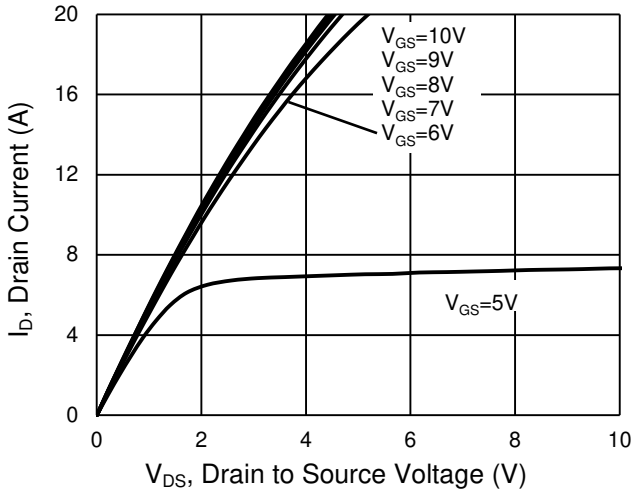
ORDERING INFORMATION

PART NO.	PACKAGE	PACKING
TSM60NB190CF C0G	ITO-220S	50pcs / Tube

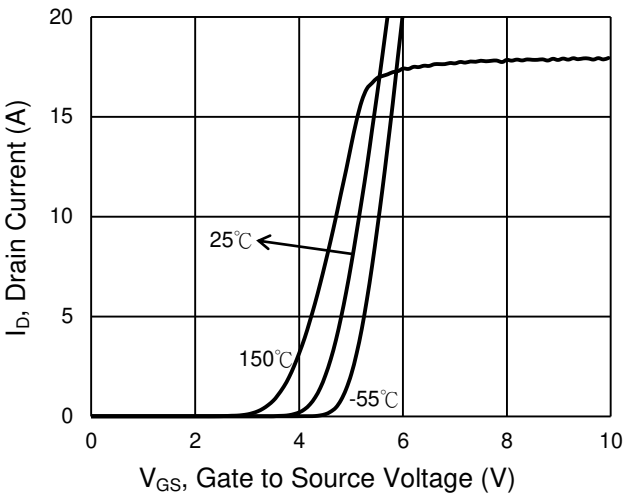
CHARACTERISTICS CURVES

(T_C = 25°C unless otherwise noted)

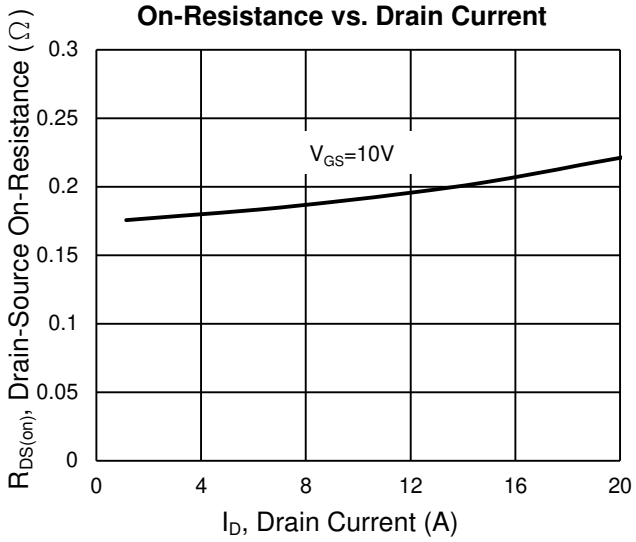
Output Characteristics



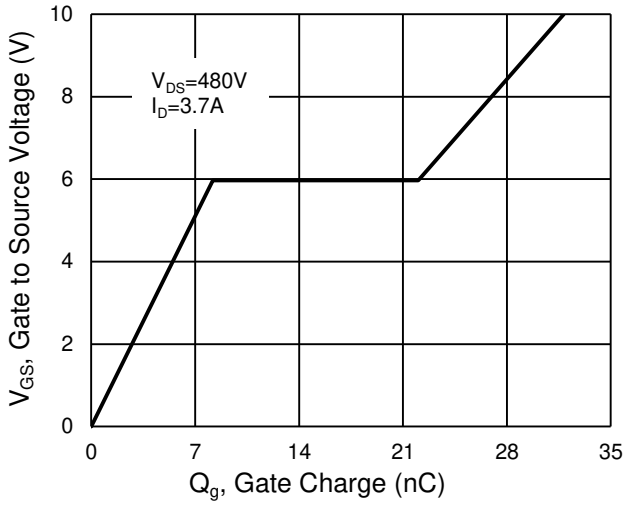
Transfer Characteristics



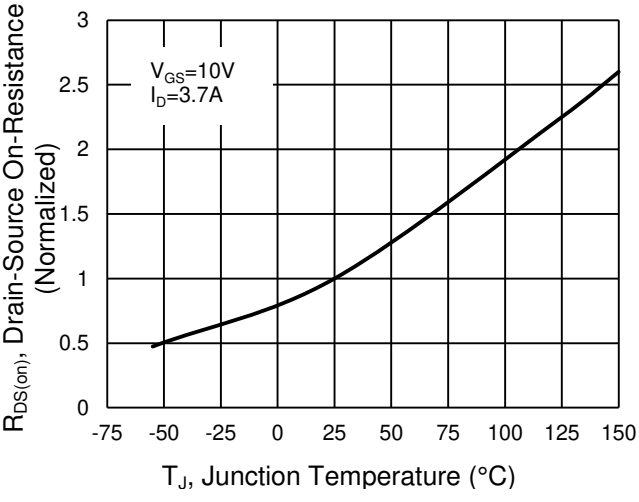
On-Resistance vs. Drain Current



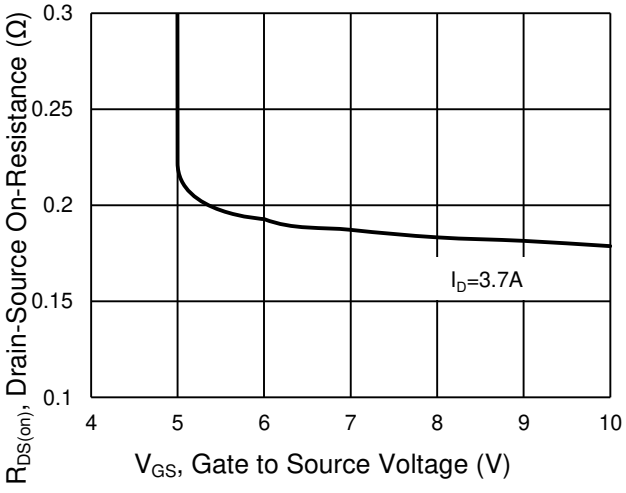
Gate-Source Voltage vs. Gate Charge



On-Resistance vs. Junction Temperature



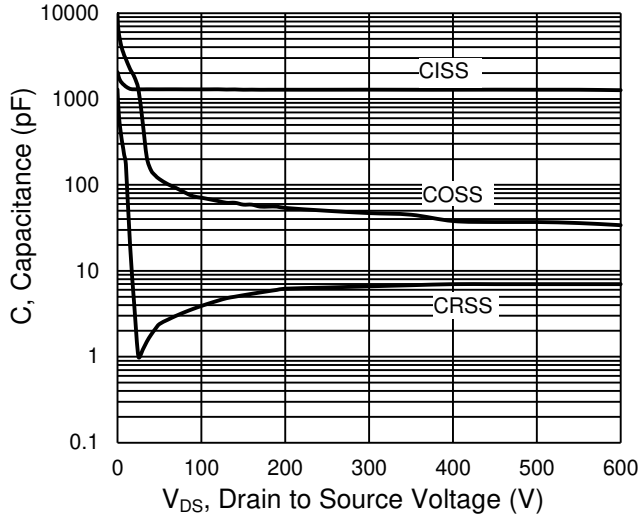
On-Resistance vs. Gate-Source Voltage



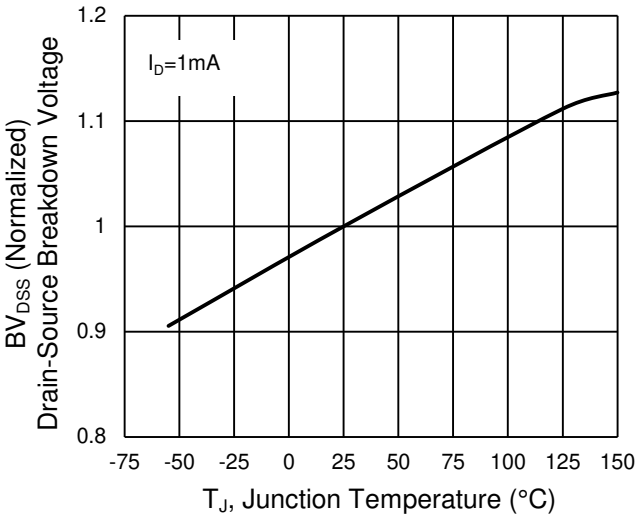
CHARACTERISTICS CURVES

(T_C = 25°C unless otherwise noted)

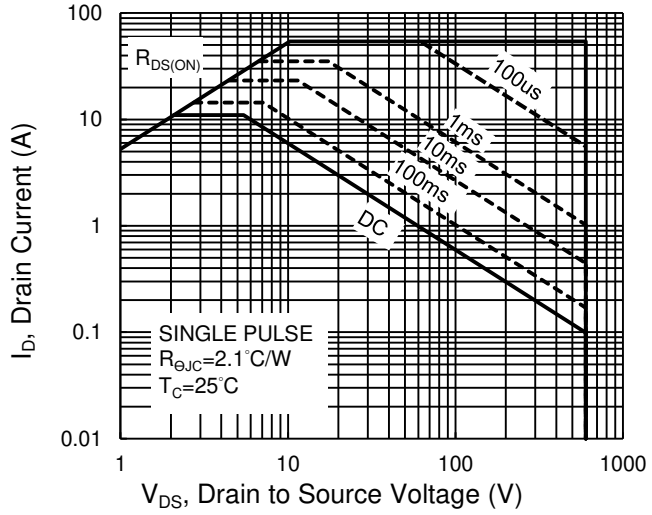
Capacitance vs. Drain-Source Voltage



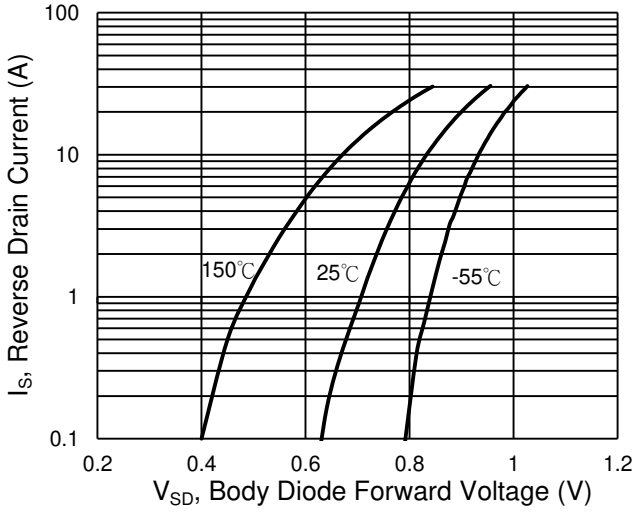
BV_{DSS} vs. Junction Temperature



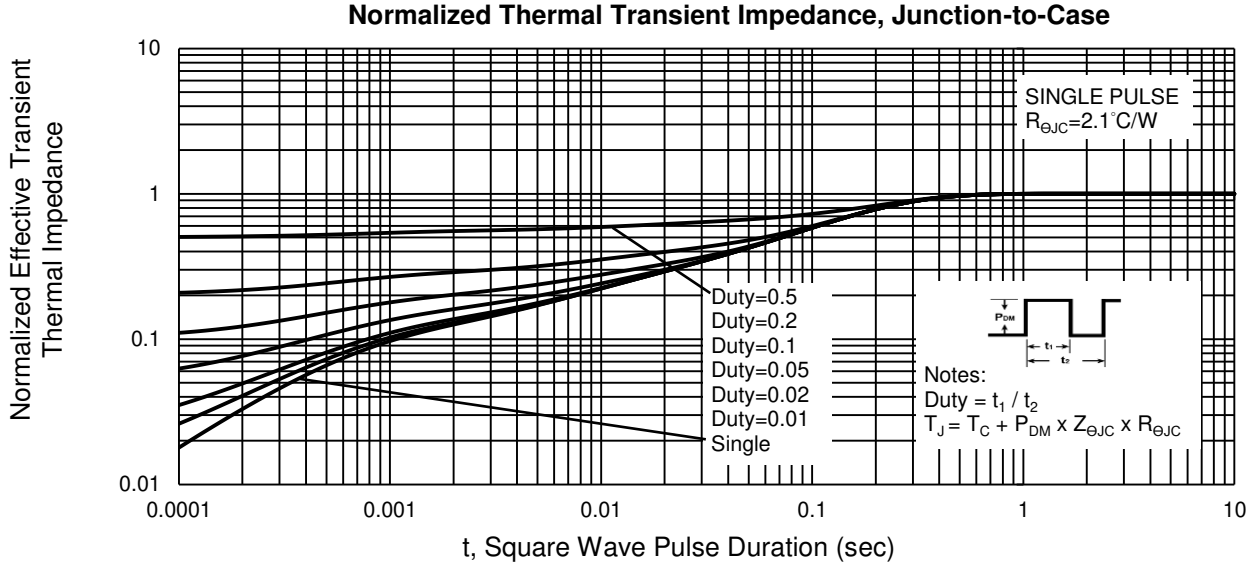
Maximum Safe Operating Area, Junction-to-Case



Source-Drain Diode Forward Current vs. Voltage

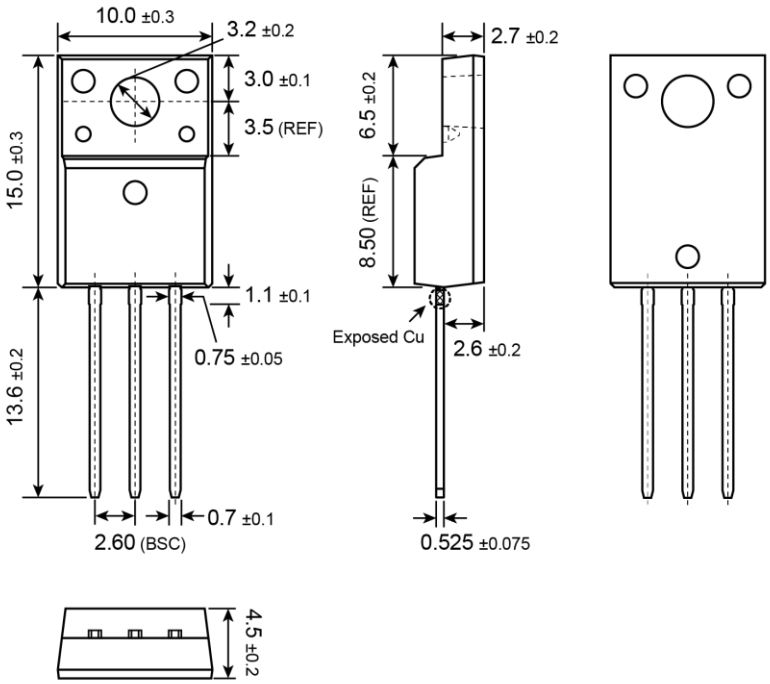


Normalized Thermal Transient Impedance, Junction-to-Case

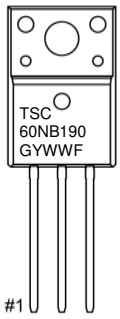


PACKAGE OUTLINE DIMENSIONS (Unit: Millimeters)

ITO-220S



MARKING DIAGRAM



G = Halogen Free
Y = Year Code
WW = Week Code (01~52)
F = Factory Code

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